

Institution of Russian Academy of Sciences INSTITUTE of AUTOMATION & CONTROL PROCESSES

of Far-Eastern Branch of RAS

5 Radio St., Vladivostok 690041, Russia Phone: +7(423) 2310439 Fax: +7(423) 2310452

e-mail: director@iacp.dvo.ru

http:www.iacp.dvo.ru

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Third Asian School-Conference on Physics and Technology of Nanostructured Materials

Participant Certificate

This is to certify that Ph.D. Olga Goroshko attended a course of lectures in the framework of the Third Asian School-Conference on Physics and Technology of Nanostructured Materials (ASCO-NANOMAT 2015) delivered by:

- 1. "Optical, ion and electron microscopies a synergy of combined application" A. Chuvilin, CIC nanoGUNE Consolider, San Sebastián, Spain
- 2. "Structure and composition of Fe-Si interfaces in (Fe/Si)₃ multilayer nanostructures" S.G.Ovchinnikov, L.V. Kirensky Institute of Physics, SB RAS, Krasnoyarsk, Russia
- 3. "Study of the properties and formation mechanisms of nanostructured functional materials" S.A. Gavrilov National Research University of Electronic Technology, Zelenograd, Russian
- 4. "Physics and application of photovoltaic perovskite nanowires" L. Forró Laboratory of Physics of Complex Matter, EPFL, Lausanne, Switzerland
- 5. "Structural control of Si based nano-structures by catalyst design" H. Tatsuoka Graduate School of Science and Technology, Shizuoka University, Hamamatsu, Japan
- "Magnetic and Magnetotransport properties of 1D magnetic nanochains" Young Keun Kim Department of Materials Science and Engineering, Korea University, Seoul, Korea
- 7. "Role of morphology on electronic properties of III-V nanowires" D. Migas Belarusian State University of Informatics and Radioelectronics, Belarus
- 8. "Sustainable materials for large area photonic applications by Design: theoretical modeling and experimental exploitation" G. Shao University of Bolton, UK
- 9. "Multi-functional manifestations of III-nitride nanostructures and films" S.M. Shivaprasad Jawaharlal Nehru Centre for Advanced Scientific Research, Bangalore, India
- 10. "Transport and optical properties of Cu₂ZnSn(S,Se)4"E. Arushanov Institute of Applied Physics, Chisinau, Moldova
- highly doped Ge layers for Si optoelectronics" 11. "Formation of strained and R.M. Bayazitov Zavoisky Physical-Technical Institute of RAS, Kazan, Russia
- 12. "Present status towards BaSi2 thin-film solar cells" T. Suemasu Institute of Applied Physics, University of Tsukuba, Tsukuba, Japan
- 13. "Modulation spectroscopy of iron silicides" Y. Terai Department of Computer Science and Electronics, Kyushu Institute of Technology, lizuka, JAPAN

14. "GeSi layers prepared on Si at high temperature of Shklyaev Institute of Semiconductor Physics of SB RAS, Novosibirsk, Russia

ASCO-NANOMAT 2015 Conference Deputy director on Scientific and Innover work of IACP FEB RAS, professor

/ Nikolay G. Galkin